

BC847AQAZ Datasheet



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DiGi Electronics Part Number BC847AQAZ-DG

Manufacturer Nexperia USA Inc.

Manufacturer Product Number BC847AQAZ

Description TRANS NPN 45V 0.1A DFN1010D-3

Detailed Description Bipolar (BJT) Transistor NPN 45 V 100 mA 100MHz 2

80 mW Surface Mount DFN1010D-3



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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
BC847AQAZ	Nexperia USA Inc.
Series:	Product Status:
	Active
Transistor Type:	Current - Collector (Ic) (Max):
NPN	100 mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, Ic:
45 V	400mV @ 5mA, 100mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
15nA (ICBO)	110 @ 2mA, 5V
Power - Max:	Frequency - Transition:
280 mW	100MHz
Operating Temperature:	Grade:
150°C (TJ)	Automotive
Qualification:	Mounting Type:
AEC-Q101	Surface Mount
Package / Case:	Supplier Device Package:
3-XDFN Exposed Pad	DFN1010D-3
Base Product Number:	
BC847	

Environmental & Export classification

8541.21.0075

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



45 V, 100 mA NPN general-purpose transistors Rev. 1 — 26 August 2015

Product data sheet

1. **Product profile**

1.1 General description

NPN general-purpose transistors in a leadless ultra small DFN1010D-3 (SOT1215) Surface-Mounted Device (SMD) plastic package with visible and solderable side pads.

Table 1. **Product overview**

Type number	Package	Package			
	Nexperia	JEITA	JEDEC		
BC847AQA	DFN1010D-3	-	-	BC857AQA	
BC847BQA	(SOT1215)			BC857BQA	
BC847CQA				BC857CQA	

1.2 Features and benefits

- General-purpose transistors
- Three current gain selections
- Low package height of 0.37 mm
- Suitable for Automatic Optical Inspection (AOI) of solder joint
- AEC-Q101 qualified

1.3 Applications

- General-purpose switching and amplification
- Mobile applications

1.4 Quick reference data

Quick reference data Table 2.

 $T_{amb} = 25 \, ^{\circ}\text{C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	45	V
I _C	collector current		-	-	100	mA
h _{FE}	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 2 \text{ mA}$				
	BC847AQA		110	-	220	
	BC847BQA		200	-	450	
	BC847CQA		420	-	800	



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2. Pinning information

Table 3. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base		•
2	Е	emitter		C I
3	С	collector		В
4	С	collector	4 3	']
			2	E sym123
			Transparent top view	

3. Ordering information

Table 4. Ordering information

Type number	Package						
	Name	Description	Version				
BC847AQA	DFN1010D-3	plastic thermal enhanced ultra thin small outline	SOT1215				
BC847BQA		package; no leads; 3 terminals; body: 1.1 × 1.0 × 0.37 mm					
BC847CQA		3 terminais, body. 1.1 × 1.0 × 0.37 mm					

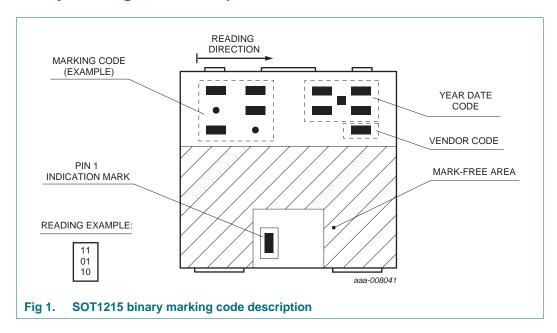
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4. Marking

Table 5. Marking codes

Type number	Marking code
BC847AQA	00 10 01
BC847BQA	00 10 11
BC847CQA	00 11 01

4.1 Binary marking code description



45 V, 100 mA NPN general-purpose transistors

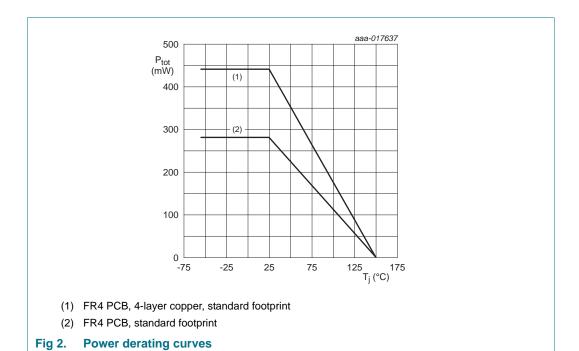
5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter	-	50	V
V _{CEO}	collector-emitter voltage	open base	-	45	V
V _{EBO}	emitter-base voltage	open collector	-	6	V
I _C	collector current		-	100	mA
I _{СМ}	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	200	mA
I _{BM}	peak base current	$\begin{array}{l} \text{single pulse;} \\ t_p \leq 1 \text{ ms} \end{array}$	-	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C			
			[1] _	280	mW
			[2] _	440	mW
Tj	junction temperature		-	+150	°C
T _{amb}	ambient temperature		-55	+150	°C
T _{stg}	storage temperature		-65	+150	°C

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, 4-layer copper; tin-plated and standard footprint.



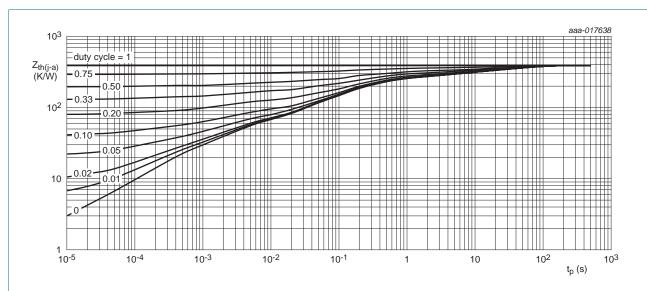
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Thermal characteristics

Table 7. Thermal characteristics

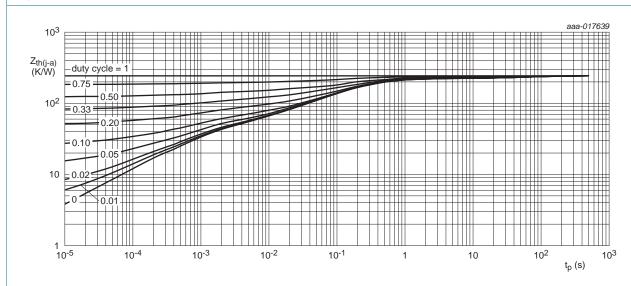
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]			446	K/W
		_	[2]	-	-	284	K/W

- Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- Device mounted on an FR4 PCB, 4-layer copper; tin-plated and standard footprint.



FR4 PCB, single-sided copper, tin-plated and standard footprint

Transient thermal impedance from junction to ambient as a function of pulse duration; typical values Fig 3.



FR4 PCB, 4-layer copper, tin-plated and standard footprint.

Fig 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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7. Characteristics

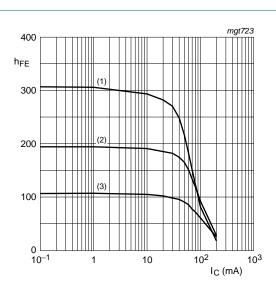
Table 8. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off	$V_{CB} = 30 \text{ V}; I_{E} = 0 \text{ A}$	-	-	15	nA
	current	$V_{CB} = 30 \text{ V}; I_E = 0 \text{ A};$ $T_j = 150 \text{ °C}$	-	-	5	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}$	-	-	100	nA
h _{FE}	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 2 \text{ mA}$				
	BC847AQA		110	-	220	
	BC847BQA		200	-	450	
	BC847CQA		420	-	800	
V _{CEsat}	collector-emitter	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$	-	90	200	mV
	saturation voltage	$I_C = 100 \text{ mA}; I_B = 5 \text{ mA}$ [1]	-	200	400	mV
V _{BEsat}	base-emitter	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$	-	700	-	mV
	saturation voltage	$I_C = 100 \text{ mA}; I_B = 5 \text{ mA}$ [1]	-	900	-	mV
V_{BE}	base-emitter voltage	$I_C = 2 \text{ mA}; V_{CE} = 5 \text{ V}$	580	660	700	mV
		$I_C = 10 \text{ mA}; V_{CE} = 5 \text{ V}$	-	-	770	mV
f _T	transition frequency	$V_{CE} = 5 \text{ V}; I_{C} = 10 \text{ mA};$ f = 100 MHz	100	-	-	MHz
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz	-	-	1.5	pF
C _e	emitter capacitance	$V_{EB} = 0.5 \text{ V}; I_C = I_c = 0 \text{ A};$ f = 1 MHz	-	11	-	pF
NF	noise figure	$I_C = 200 \ \mu A; \ V_{CE} = 5 \ V;$ $R_S = 2 \ k\Omega; \ f = 1 \ kHz;$ $B = 200 \ Hz$	-	2	10	dB

^[1] Pulse test: $t_p \le 300 \ \mu s; \ \delta = 0.02.$

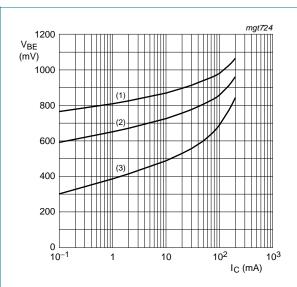
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$$V_{CE} = 5 V$$

- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -55 \, ^{\circ}C$

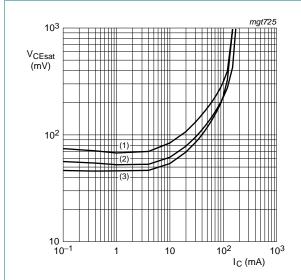
Fig 5. BC847AQA: DC current gain as a function of collector current; typical values



$$V_{CE} = 5 V$$

- (1) $T_{amb} = -55 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = 150 \, ^{\circ}C$

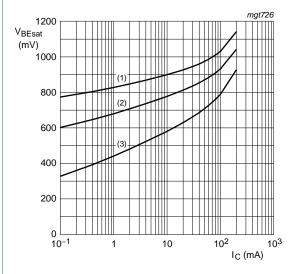
Fig 6. BC847AQA: Base-emitter voltage as a function of collector current; typical values





- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -55 \, ^{\circ}C$

Fig 7. BC847AQA: Collector-emitter saturation voltage as a function of collector current; typical values

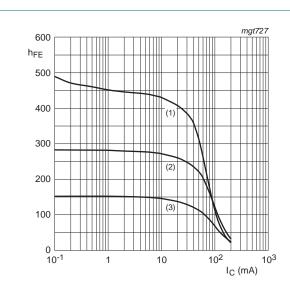


$$I_{\rm C}/I_{\rm B} = 10$$

- (1) $T_{amb} = -55 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = 150 \, ^{\circ}C$

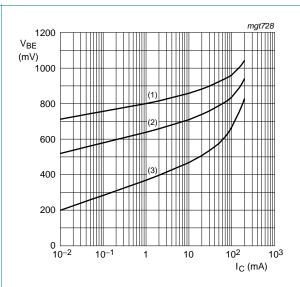
Fig 8. BC847AQA: Base-emitter saturation voltage as a function of collector current; typical values

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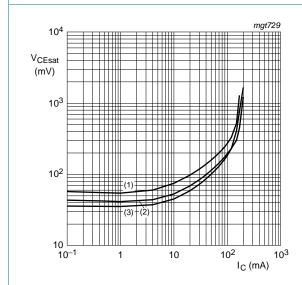
- $V_{CE} = 5 V$
- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -55 \, ^{\circ}C$

Fig 9. BC847BQA: DC current gain as a function of collector current; typical values



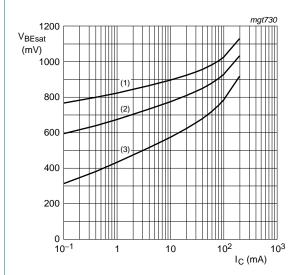
- $V_{CE} = 5 V$
- (1) $T_{amb} = -55 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = 150 \, ^{\circ}C$

Fig 10. BC847BQA: Base-emitter voltage as a function of collector current; typical values



- $I_{\rm C}/I_{\rm B} = 20$
- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -55 \, ^{\circ}C$

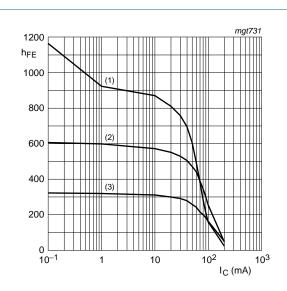
Fig 11. BC847BQA: Collector-emitter saturation voltage as a function of collector current; typical values



- $I_{\rm C}/I_{\rm B} = 10$
- (1) $T_{amb} = -55 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = 150 \, ^{\circ}C$

Fig 12. BC847BQA: Base-emitter saturation voltage as a function of collector current; typical values

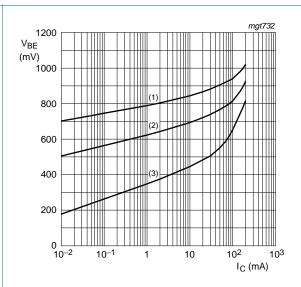
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$$V_{CE} = 5 V$$

- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -55 \, ^{\circ}C$

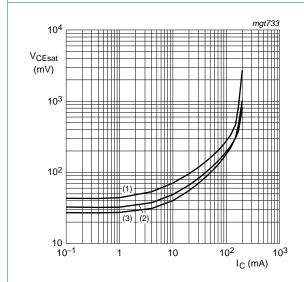
Fig 13. BC847CQA: DC current gain as a function of collector current; typical values



$$V_{CE} = 5 \text{ V}$$

- (1) $T_{amb} = -55 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = 150 \, ^{\circ}C$

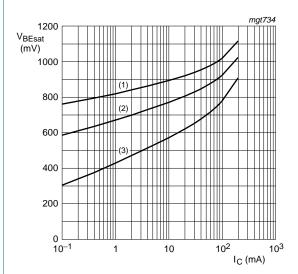
Fig 14. BC847CQA: Base-emitter voltage as a function of collector current; typical values





- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -55 \, ^{\circ}C$

Fig 15. BC847CQA: Collector-emitter saturation voltage as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 10$$

- (1) $T_{amb} = -55 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = 150 \, ^{\circ}C$

Fig 16. BC847CQA: Base-emitter saturation voltage as a function of collector current; typical values

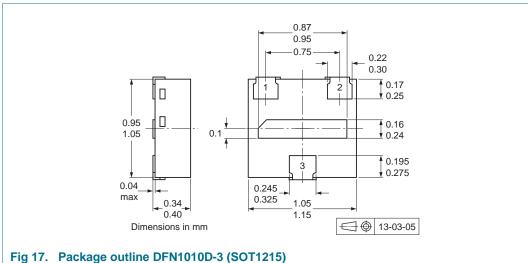
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Test information

8.1 Quality information

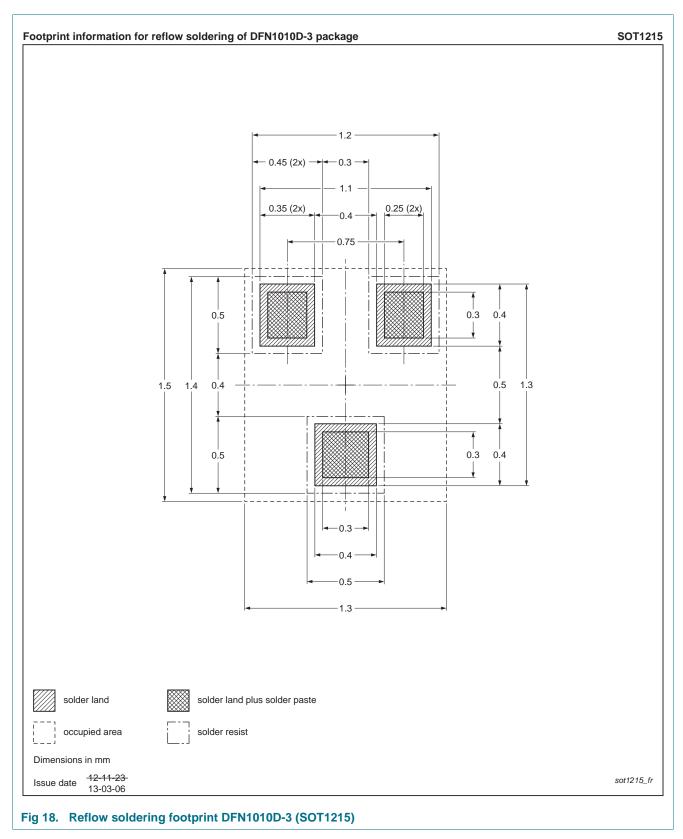
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

Package outline 9.



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10. Soldering



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11. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BC847XQA_SER v.1	20150826	Product data sheet	-	-

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12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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